

atomera

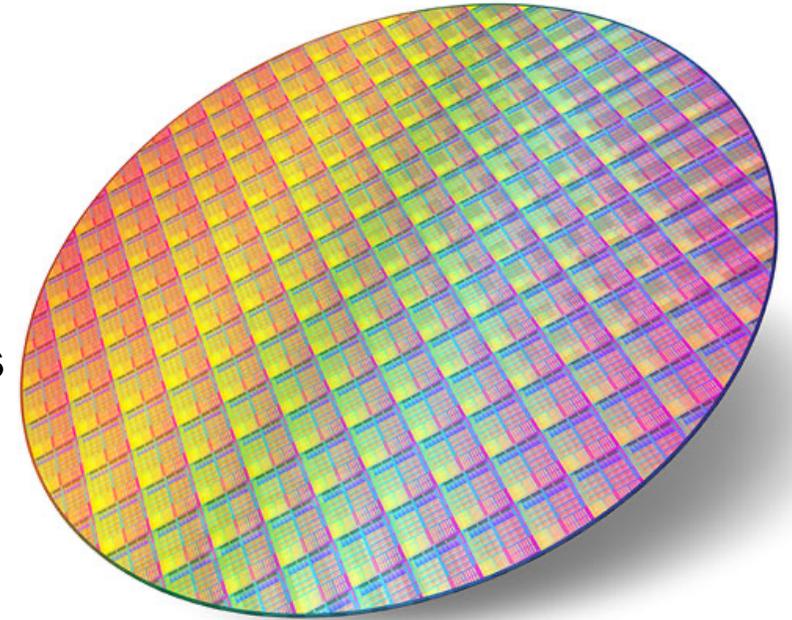
Investor Presentation

February 2022

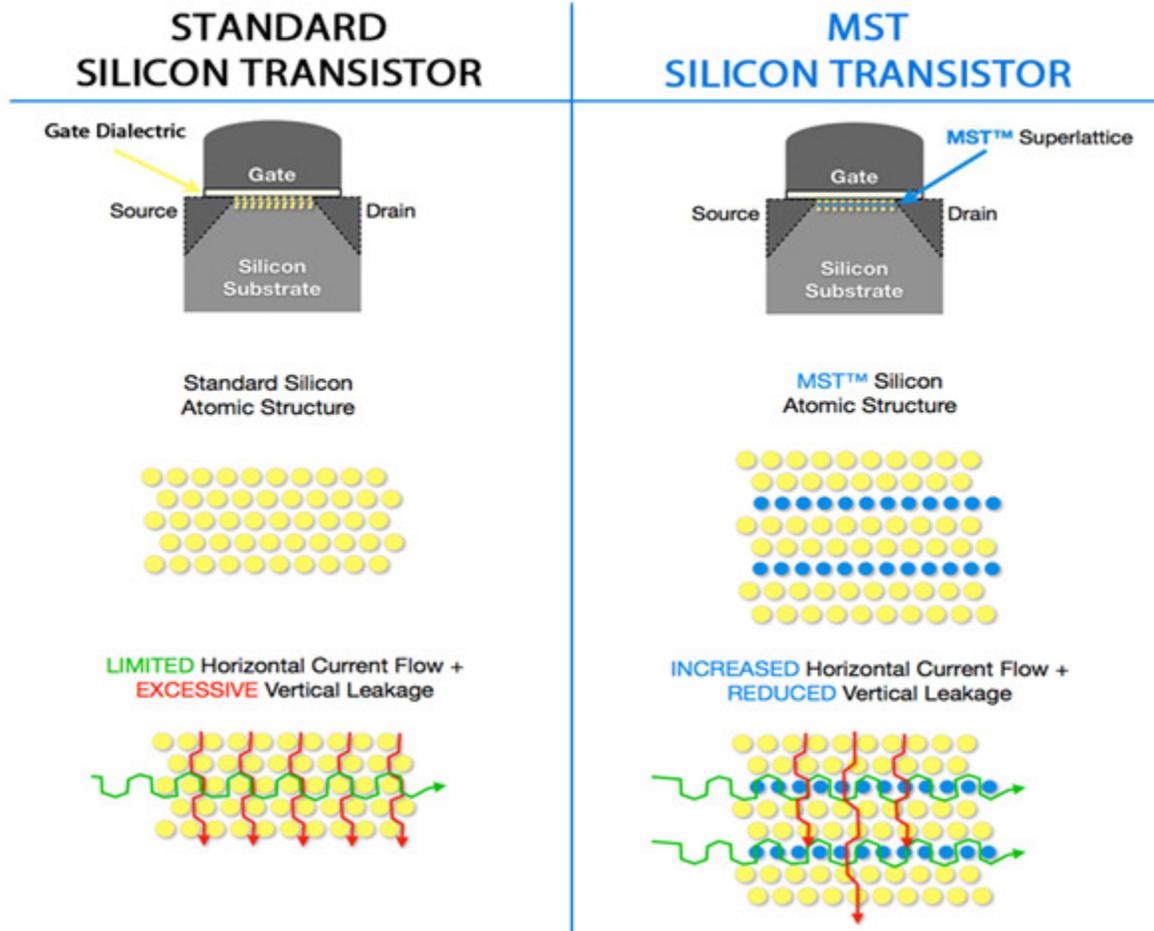
This presentation contains forward-looking statements concerning Atomera Incorporated (“Atomera,” the “Company,” “we,” “us,” and “our”). The words “believe,” “may,” “will,” “potentially,” “estimate,” “continue,” “anticipate,” “intend,” “could,” “would,” “project,” “plan,” “expect” and similar expressions that convey uncertainty of future events or outcomes are intended to identify forward-looking statements. These forward-looking statements are subject to a number of risks, uncertainties and assumptions, including those disclosed in the section “Risk Factors” included in our Annual Report on Form 10-K filed with the SEC on February 15, 2022. In light of these risks, uncertainties and assumptions, the forward-looking events and circumstances discussed in this presentation may not occur and actual results could differ materially and adversely from those anticipated or implied in our forward-looking statements. You should not rely upon forward-looking statements as predictions of future events. Although we believe that the expectations reflected in our forward-looking statements are reasonable, we cannot guarantee that the future results, levels of activity, performance or events and circumstances described in the forward-looking statements will be achieved or occur.

This presentation contains only basic information concerning Atomera. The Company’s filings with the Securities Exchange Commission, including the Prospectus Supplement , include more information about factors that could affect the Company’s operating and financial results. We assume no obligation to update information contained in this presentation. Although this presentation may remain available on the Company’s website or elsewhere, its continued availability does not indicate that we are reaffirming or confirming any of the information contained herein.

- ▶ **Mears Silicon Technology (MST[®]) is a thin film used to enhance semiconductors**
 - Results in higher performance, lower power, and lower costs for ICs
- ▶ **Capital-light IP and technology licensing business**
 - Robust and growing patent portfolio
- ▶ **Engaged with 50% of world's top semiconductor makers**
- ▶ **Licenses with four companies including recent JDA**
- ▶ **Strong team to commercialize technology**



Potential Benefits



► Improved Efficiency

- Higher transistor performance
- Lower power consumption
- Better reliability

► Lower cost

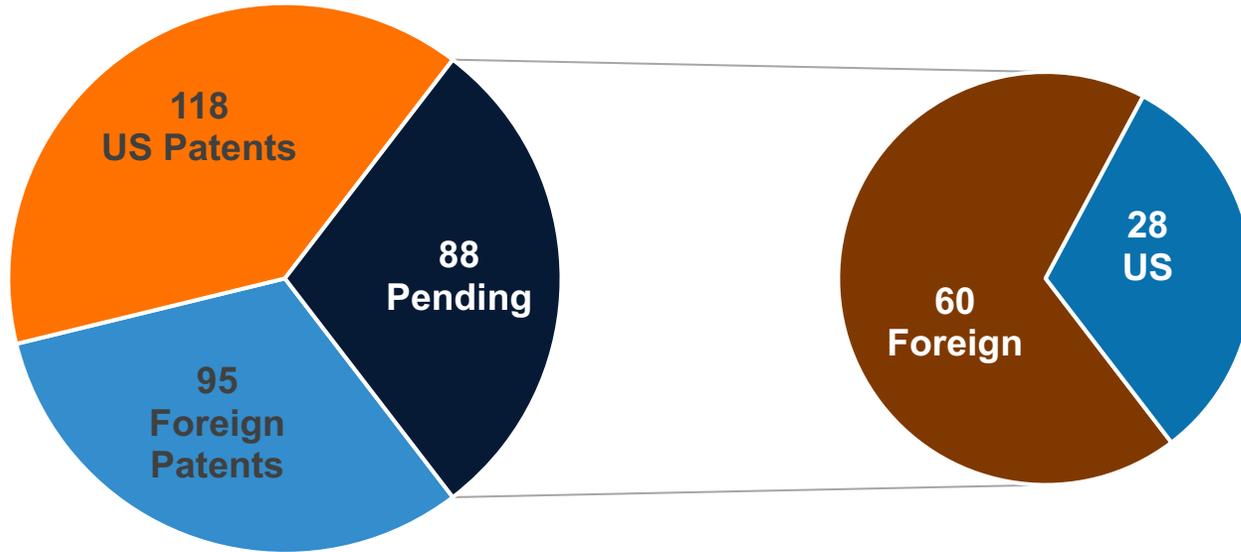
- Reduced die size
- Improved yield
- Higher throughput

► Same benefits as a node shrink

IP Portfolio Grew 14% YoY



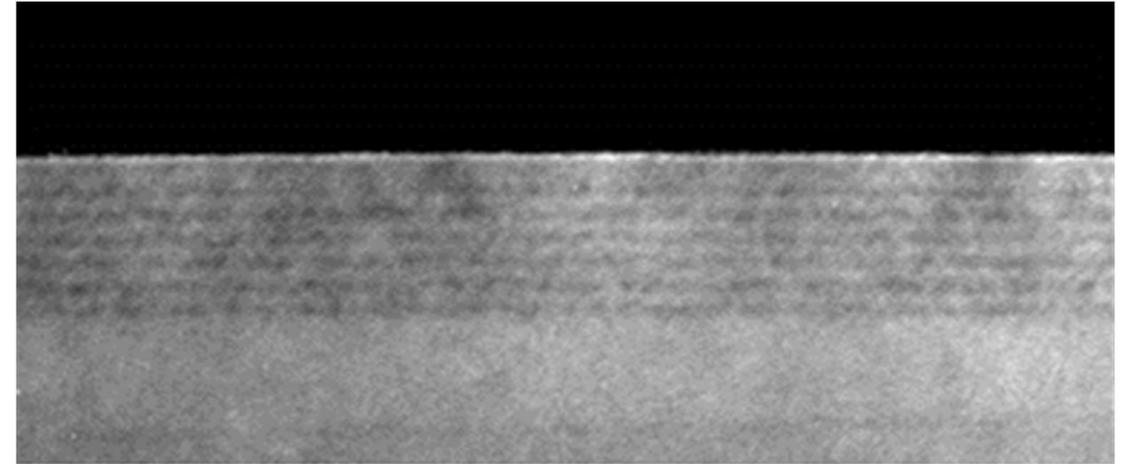
301 Patents Issued and Pending



Core MST Method and Device
MST Enabled Devices/Architecture
Next-Gen Architectures using MST

Discoverable

These distinctive layers are visible on products using MST



Extensive know-how

Extends life and value of patents

Target Customers & Partners



Integrated Device Manufacturers



Foundry



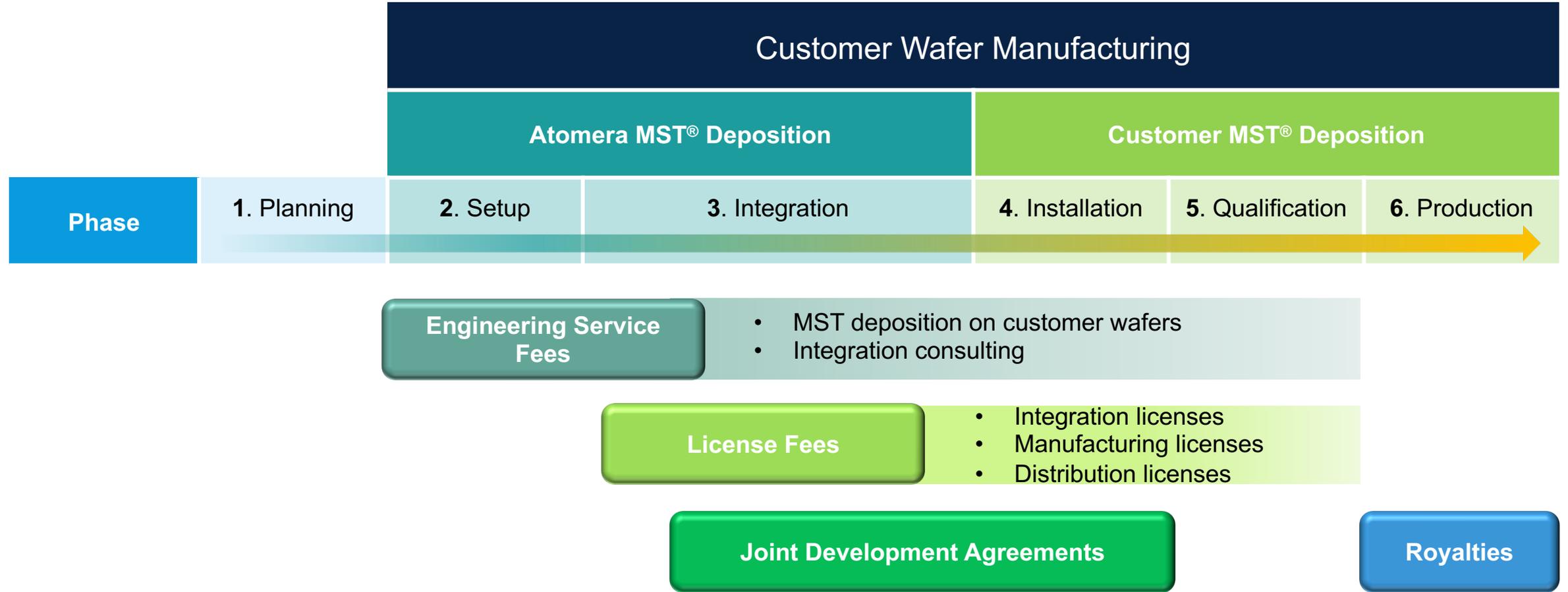
Fabless



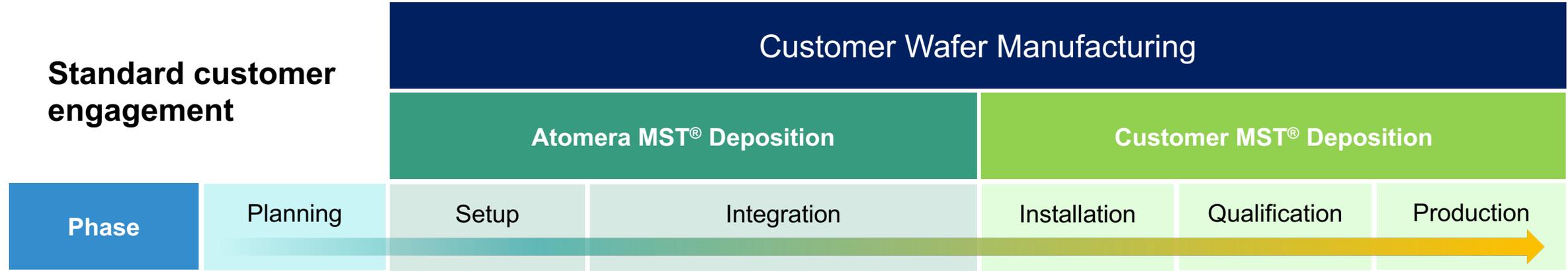
Tool Suppliers (Partners)



Customer Engagement & Revenue Model



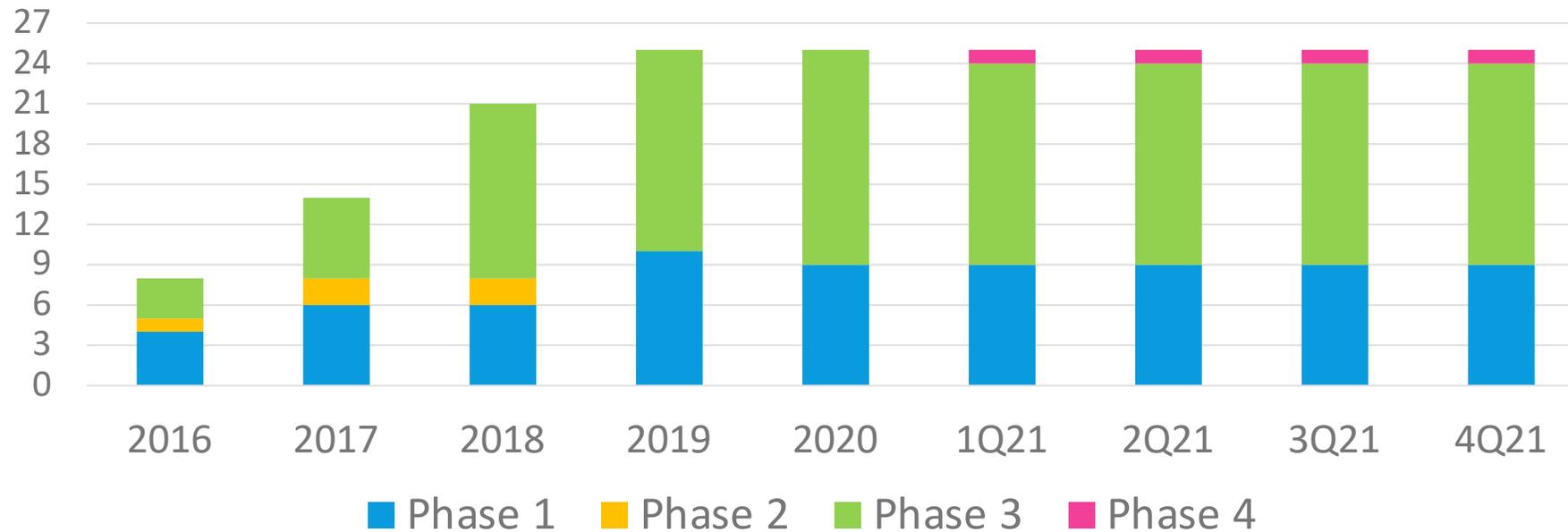
Customer Engagement Model



Customer Pipeline



Number of Customer Engagements

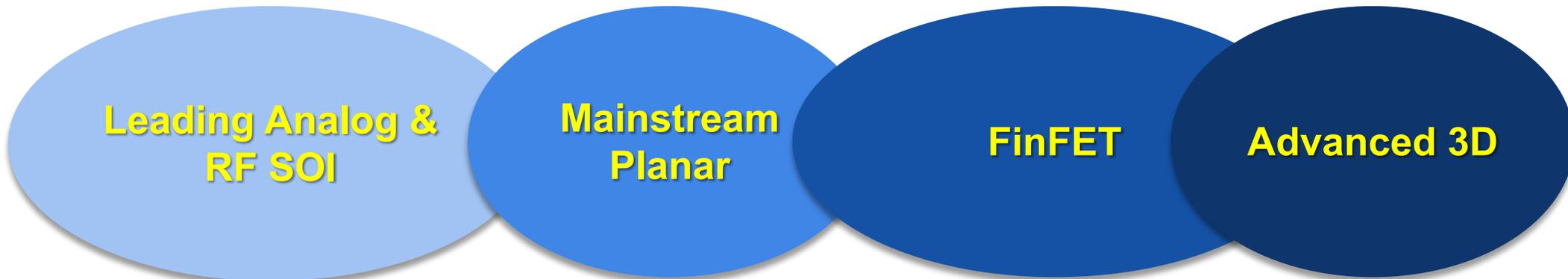


- 19 customers, 25 engagements
- Working with 50% of the world's top semiconductor makers*

• 10 of the top 20 (IC Insights, McClean Report 2021)

^ End of year engagement count, plus CY quarters

MST Key Benefits Across Nodes

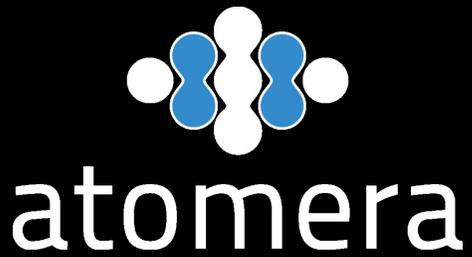


Mobility	8%	25%	10%	<5%								
Dopant Engineering MST-SP	20%	15%	15%	20%								
TDDB/BTI (enables overdrive) PNO & HKMG gate stacks		25%	25%	25%								
	180nm	130nm	90nm	65nm	40nm	28nm	22nm	16nm	14nm	10nm	7nm	5nm

These Benefits are ADDITIVE & COMPLEMENTARY to other enhancement technologies



MST technology focus areas



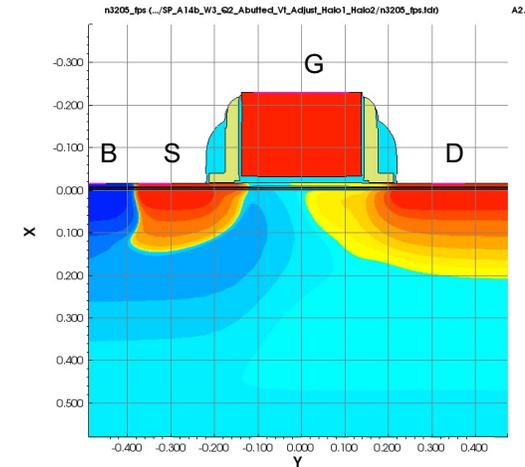
MST-SP

MST for
Advanced
Nodes

MST for
RF-SOI



- ▶ **MST-SP is a highly-engineered asymmetric power device**
 - Uses MST to enhance I_{dlin} and precisely control dopant profiles
- ▶ **Improves 5V power devices**
 - Lower R_{SP}
 - Can be traded for up to 20% smaller area
- ▶ **Targeted for rapidly-growing PMIC market**



5V Transistors – Critical and Growing Market



- ▶ **Targeted at rapidly-growing PMIC (Power Management IC) market**
 - Power devices can be up to 80% of PMIC die area
- ▶ **All ICs need stable, regulated power**
 - Across battery charge level, lifetime degradation, and load
 - Across usage modes – DVS (Dynamic Voltage Scaling), sleep, others
- ▶ **5V transistor required to deliver IC power from any source**
 - Battery-powered, USB, wall connected
- ▶ **5V devices do not scale with Moore’s Law**
- ▶ **MST SP allows significant scaling of gate length, and a performance boost**

THE WALL STREET JOURNAL.

“A typical 5G smartphone can hold as many as eight power-management chips, compared with two to three in a 4G phone, according to Hui He, an analyst at research firm Omdia.”

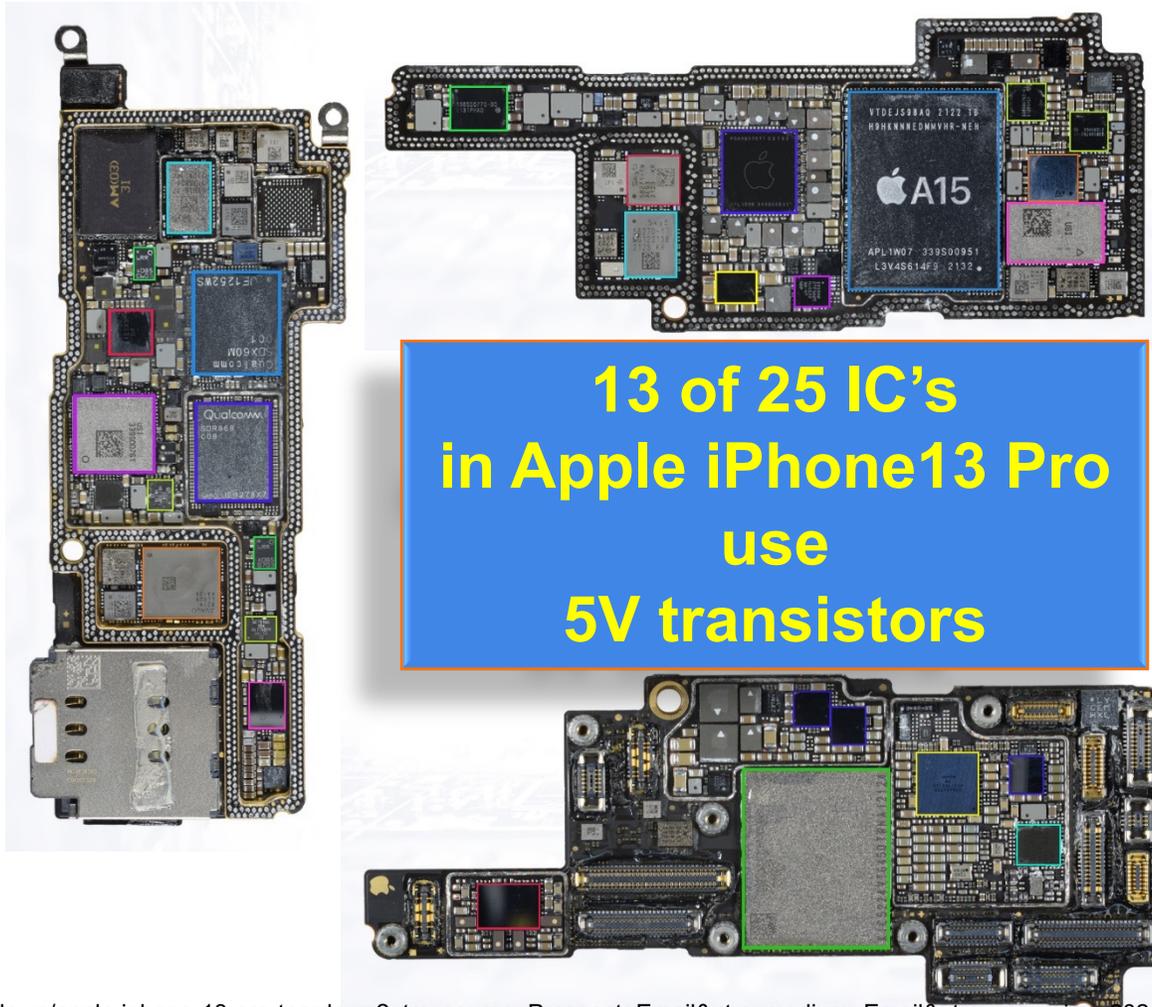
WSJ “Why the Chip Shortage is So Hard to Overcome” 4/20/2021

2018-2025F IC Market Forecast by Device Type (Analog)

Product Category	18	19	19/18 % Chng	20	20/19 % Chng	21F	21/20 % Chng	22F	22/21 % Chng	23F	23/22 % Chng	24F	24/23 % Chng	25F	25/24 % Chng	20-25 CAGR
Power Management (\$M)	14,529	14,050	-3%	14,640	4%	18,153	24%	20,332	12%	22,568	11%	23,019	2%	24,861	8%	11%
Units (M)	69,243	67,227	-3%	68,409	2%	80,788	18%	91,396	13%	102,475	12%	105,580	3%	115,178	9%	11%
ASP (\$)	\$0.21	\$0.21	0%	\$0.21	2%	\$0.22	5%	\$0.22	-1%	\$0.22	-1%	\$0.22	-1%	\$0.22	-1%	0%

Source: IC Insight’s McClean Report, June 2021

Example: Use Of 5V Transistor In Apple iPhone13



- Qualcomm Snapdragon X60 5G Modem
- Qualcomm RF Transceiver
- USI Wi-Fi/BT Wireless Combo Module
- Qualcomm PMX60 PMIC
- STMicroelectronics Secure MCU/eSIM
- Qorvo Envelope Tracker IC (2 pcs, likely)
- Qualcomm Envelope Tracker IC
- Avago Front-End Module
- Broadcom Wireless Charging Receiver IC

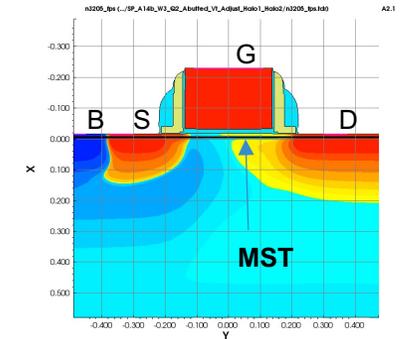
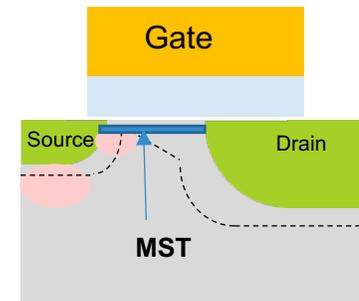
- Apple APL1W07 A15 Bionic PoP (A15 AP + SK hynix 6GB LPDDR4X SDRAM)
- Apple APL1098 PMIC
- NXP Display Port Multiplexer
- Skyworks SKY58271-19 Front-End Module
- Skyworks SKY58270-17 Front-End Module
- Apple/Dialog Semi 338S00770-B0 PMIC
- Apple/Dialog Semi 338S00762-A1 PMIC
- STMicroelectronics STB601A05 PMIC
- USI Apple U1 UWB Module
- Texas Instruments TPS65657B0 Display Power Supply
- KIOXIA 256 GB NAND Flash
- Apple/Cirrus Logic Audio Codec
- NXP SN210 NFC & Secure Element
- Apple/Cirrus Logic Audio Amplifier
- Apple/Cirrus Logic Power Conversion

- iPhone 13 Pro teardown by Tech Insights
- 5V transistor assessment by Atomera

Reference https://www.techinsights.com/blog/teardown/apple-iphone-13-pro-teardown?utm_source=Prospect+Email&utm_medium=Email&utm_campaign=2021+-+Q3+-+Teardown+-+Blog+-+Apple+iPhone+13

5V MST-SP Product – Value Proposition

- ▶ **Industry best performance at 180nm (Rsp)**
 - Based on measured silicon data
 - Scalable to smaller process nodes
- ▶ **Meets all reliability requirements**
 - Breakdown Voltage (BVDSS) > 10.5V
- ▶ **Significant cost savings, performance benefits**
 - Die area reduction up to 20%
- ▶ **Demonstrates the big advantage MST can bring to highly optimized designs**
- ▶ **Complete design package accelerates time to production**



Royalty Opportunity



- ▶ ~370 wafer fabs operating worldwide
- ▶ Adoption of MST in one fab can make Atomera profitable from royalties alone
 - 2021 non-GAAP OPEX guidance is \$14.00-14.5M

Example 1 Worldwide Average Fab	
Monthly Fab Capacity ¹ (wafers/month)	49,000
Industry average wafer ASP - 2018	\$1,136
Annual Revenue Potential²	\$13M
Annual Revenue at 50% of ramp ²	\$6.7M

Example 2 Leading Foundry, 28nm Fab	
Monthly Fab Capacity (wafers/month)	80,000
Industry average 28nm wafer ASP	\$3,000
Annual Revenue Potential²	\$58M
Annual Revenue at 50% of ramp ²	\$29M

1. Represents wafers starts per month (200mm equiv) – 217.3M starts in 370 fabs

2. Assumes 2% royalty rate

Source: IC Insights Global Wafer Capacity 2019-2023 report, McClean Report 2019

MST Customer Business Opportunity



▶ Standard industry fab wafer pricing, GM, and cost

	Price	GM%	GM\$ Increase	MST Royalty	Cost	
28nm HP wafer	\$ 3,000	45%	\$ -	\$ -	\$ 1,650	
28nm HP+ wafer	\$ 3,150					\$150 price increase for +15% performance

▶ Fab gets a 30% performance improvement or 25% shrink via MST

MST processing cost					\$ 20	Incremental cost of depositing MST
28nm HP wafer with MST	\$ 3,300	47.4%	\$ 214	\$ 66	\$ 1,736	\$300 price increase for +30% performance
28nm HP wafer with MST	\$ 3,375	48.5%	\$ 288	\$ 68	\$ 1,738	12.5% price increase for 25% size reduction

▶ Fabless customer benefit in die shrink case

	Chip sales/ wafer*	GM%	GM\$ Increase	Product ASP	Die/wafer	
28nm HP wafer	\$ 8,400	50.0%	\$ -	\$ 4.42	2,235	Baseline business for 30mm ² chip
28nm HP wafer with MST	\$ 11,279	62.8%	\$ 2,879	\$ 4.42	3,001	Improved financials with 25% size reduction

▶ Everyone in the value chain benefits from MST technology

* Yielded

Financial Review



	Q4 '20	FY 2020	Q1 '21	Q2 '21	Q3 '21	Q4 '21	FY 2021	Balance Sheet 12/31/21	
GAAP Results									
Revenue	\$ -	\$0.06M	\$0.4M	\$ -	\$ -	\$ -	\$0.4M	Cash	\$28.7M
Gross Profit	\$ -	\$0.05M	\$0.4M	\$ -	\$ -	\$ -	\$0.4M	Debt	-
Operating Expense								Shares Outstanding	23.2M
R&D	\$2.2M	\$8.4M	\$2.2M	\$2.1M	\$2.2M	\$2.2M	\$8.8M		
G&A	\$1.4M	\$5.6M	\$1.5M	\$1.5M	\$1.6M	\$1.5M	\$6.2M		
S&M	\$0.3M	\$0.9M	\$0.3M	\$0.1M	\$0.3M	\$0.3M	\$1.0M		
Total Operating Expense	\$3.9M	\$15.0M	\$4.0M	\$3.7M	\$4.1M	\$4.1M	\$15.9M		
Net Loss	(\$3.9M)	(\$14.9M)	(\$3.6M)	(\$3.7M)	(\$4.2M)	(\$4.2M)	(\$15.7M)		
Loss Per Share	(\$0.19)	(\$0.79)	(\$0.16)	(\$0.17)	(\$0.19)	(\$0.18)	(\$0.70)		
GAAP/Non-GAAP Reconciliation									
Net Loss (GAAP)	(\$3.9M)	(\$14.9M)	(\$3.6M)	(\$3.7M)	(\$4.2M)	(\$4.2M)	(\$15.7M)		
Stock-Based Compensation	\$0.8M	\$3.0M	\$0.7M	\$0.8M	\$0.8M	\$0.6M	\$3.0M		
Other income (expense)*	-	\$0.2M	-	-	\$0.1M	\$0.3M	\$0.3M		
Adjusted EBITDA (Non-GAAP)**	(\$3.0M)	(\$11.7M)	(\$2.9M)	(\$2.9M)	(\$3.4M)	(\$3.4M)	(\$12.5M)		

Some figures may not total exactly due to rounding

*Includes depreciation, interest income/expense and provision for income tax

**Adjusted EBITDA is a non-GAAP financial measure. A full reconciliation of GAAP and non-GAAP results is contained in our press release.

Summary



- ▶ High margin, recurring revenue financial model
- ▶ Strong technology, patent position, and balance sheet
- ▶ Traction with many top industry players and growing licensee base
- ▶ Ramping commercial license revenues



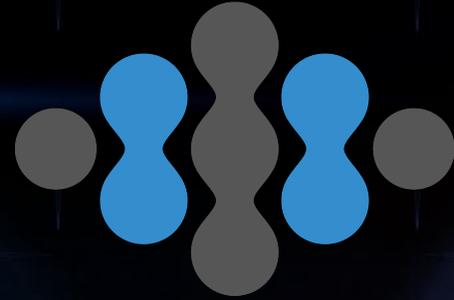
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Thank You

New Board Member



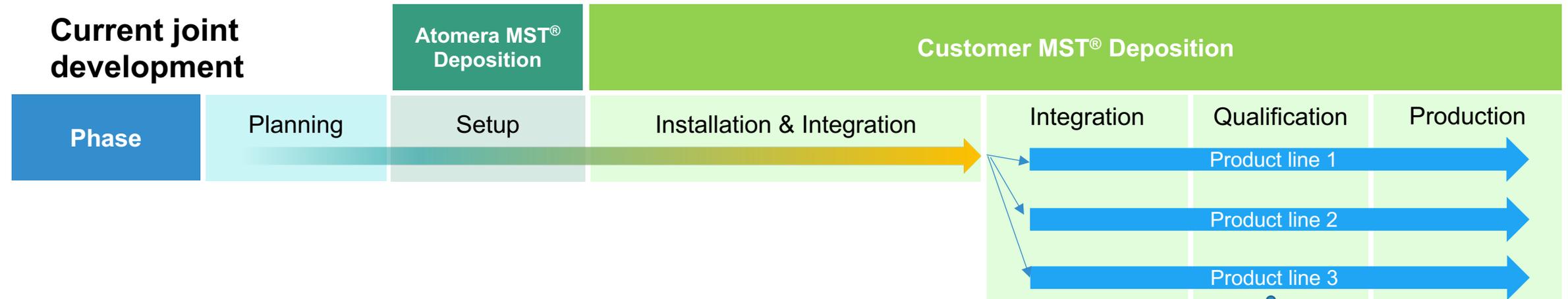
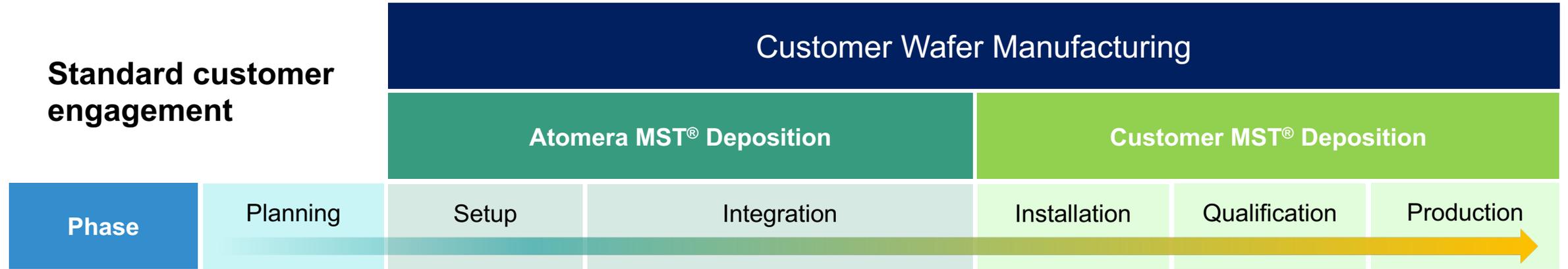
- ▶ **Suja Ramnath**
- ▶ **CEO & President – Integra Technologies**
- ▶ **Deep semiconductor business experience**
 - Division GM Analog devices
 - Senior VP and GM MACOM Technology Solutions
 - RF Micro Devices
 - Electrical engineer



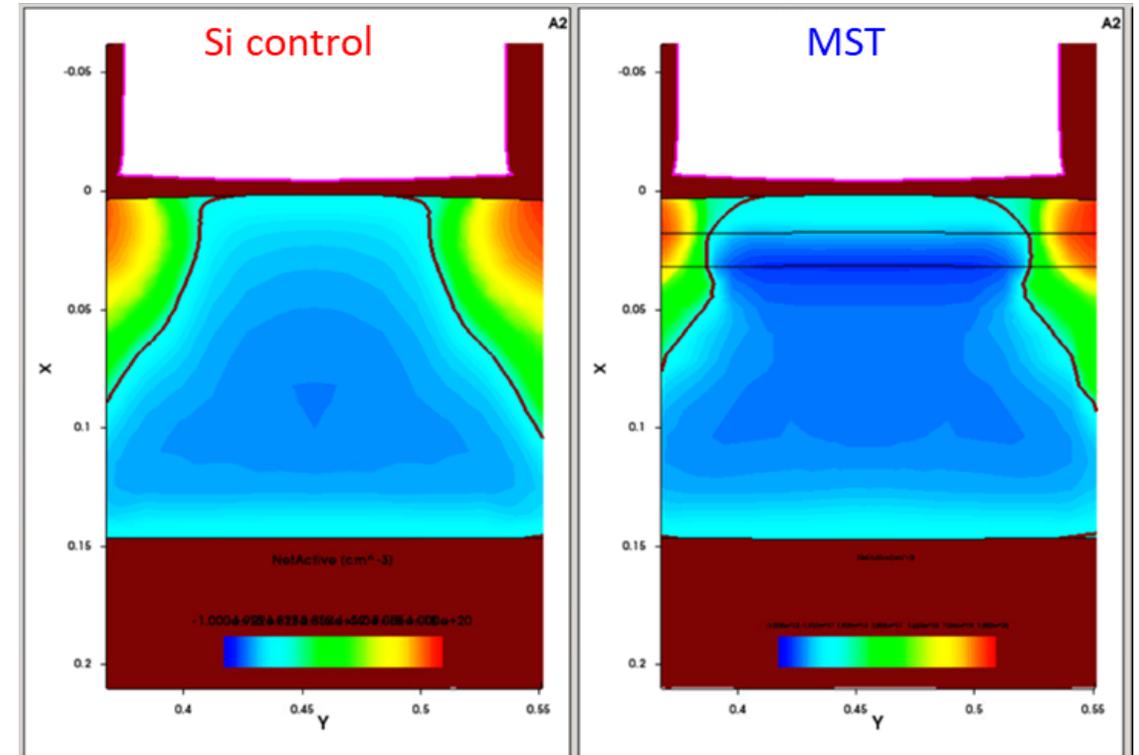
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Backup Slides

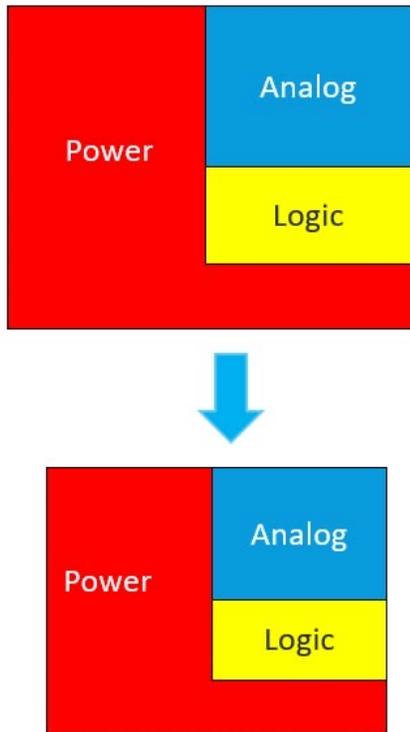
Customer Engagement Model



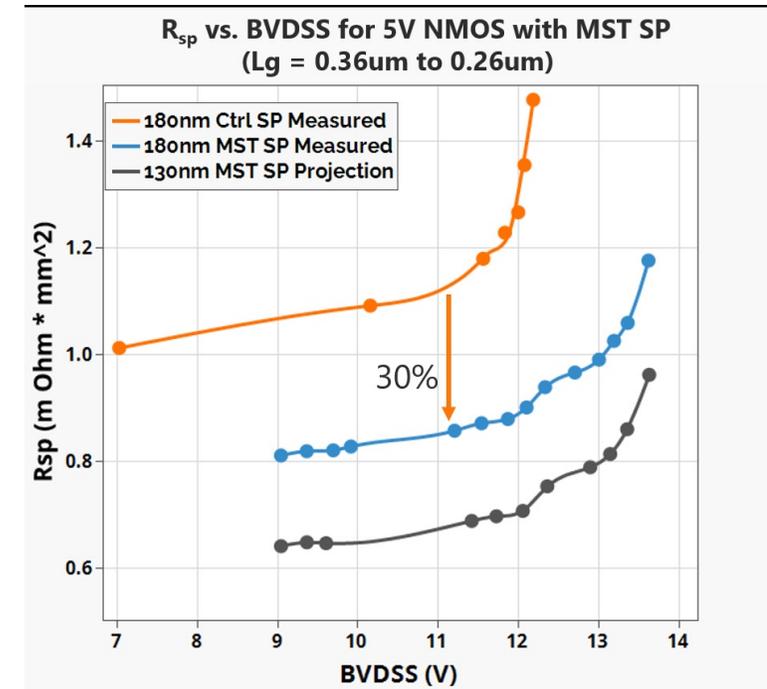
- ▶ **Leading semiconductor companies use TCAD to model manufacturing processes**
 - MSTcad is an add-on for MST
- ▶ **MSTcad can speed up the time needed to evaluate multiple MST integration options**
- ▶ **Lowers cost of MST evaluation**
- ▶ **Speeds time to successful wafer runs**
- ▶ **Fewer wafer runs lead to faster production**



MST enables legacy capacity expansion

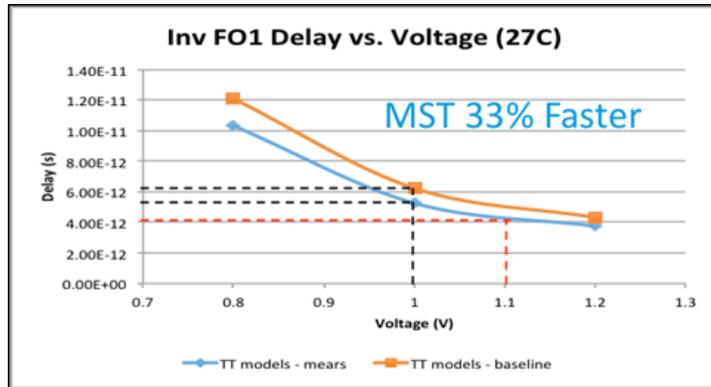


- ▶ **MST provides 30% performance advantage**
 - 0.13u analog design
 - MST vs control silicon
- ▶ **Enables a die shrink of 15-20%**
- ▶ **Smaller die means more manufacturing capacity**
 - Without the cost of building a new fab



MST 28nm benefits

MST shows 30% higher performance



MST performance improvement due to:

- Higher electron mobility
- Improved gate oxide integrity enabling higher overdrive

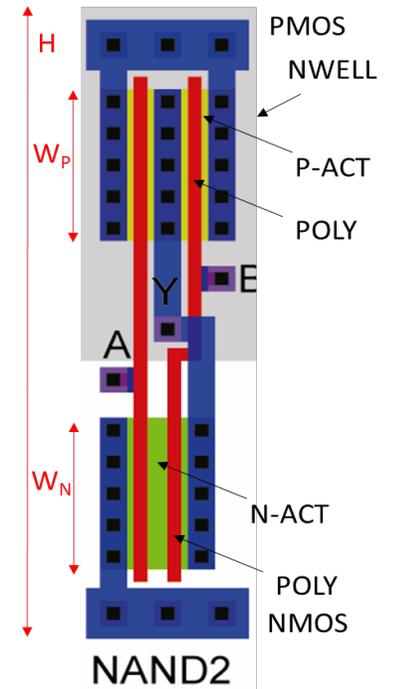
▶ **Performance improvements due to MST can be traded for area reduction**

▶ **28nm PDK SPICE model used to showcase:**

- Logic scaling with MST shows 22-25% area reduction
 - Using a NAND2 gate
- Analog scaling with MST shows up to 21% area reduction

▶ **Implementation of MST on new 28nm designs can result in >20% more production capacity**

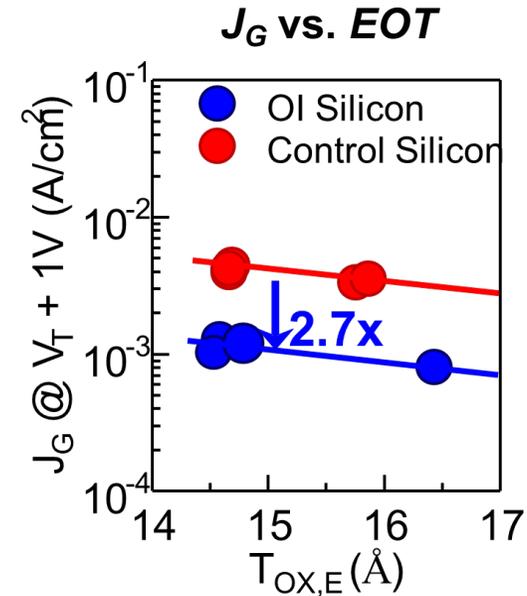
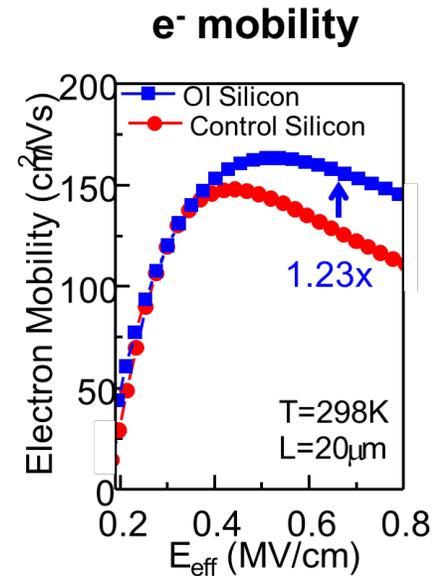
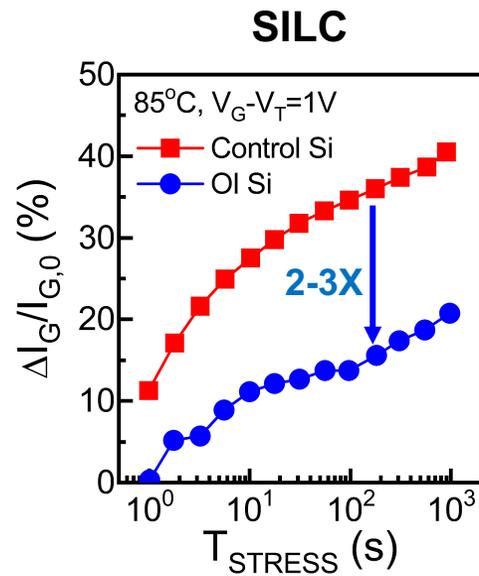
▶ **Allows excellent economic benefits for the whole value chain**



MST for High-k metal gate (HKMG) transistors

► MST enhances HKMG transistor performance and reliability*

- Reduced stress induced leakage current (SILC) enabling reliability improvement
- 23% long-channel mobility enhancement
- 2.7x lower gate leakage



* Professor Suman Datta Group



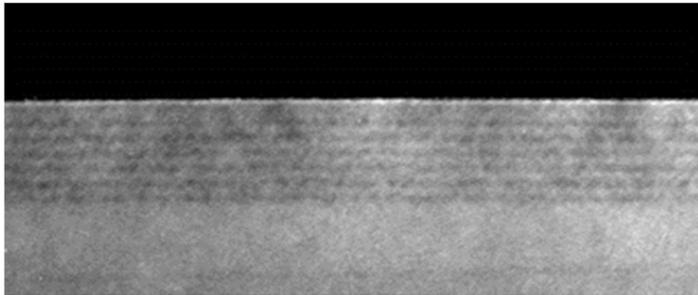
Joint Development Agreements



- ▶ Advantages of joint development
 - Atomera and customer engineers aligned on common goal
 - Customer “resident expert” team develops expertise on Atomera technology
 - Resident experts become natural advocates
- ▶ First JDA signed with market leading semiconductor company
 - Includes a manufacturing license, putting them in Phase 4
 - Upon completion, MST can more easily be adopted by business units
 - Each business unit is an incremental licensing opportunity

Quantum Engineered Silicon

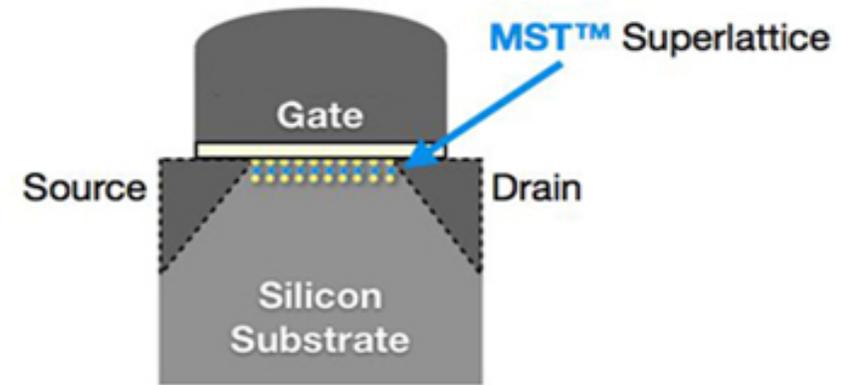
Partial Monolayers of Oxygen in Silicon

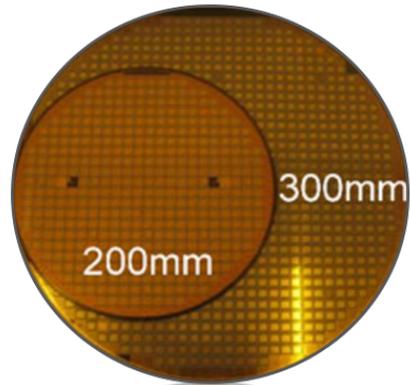


Supported by
Major Semiconductor
Tool Suppliers



MST Enhanced Transistors





Epi Deposition Tool

▶ Epi deposition facility

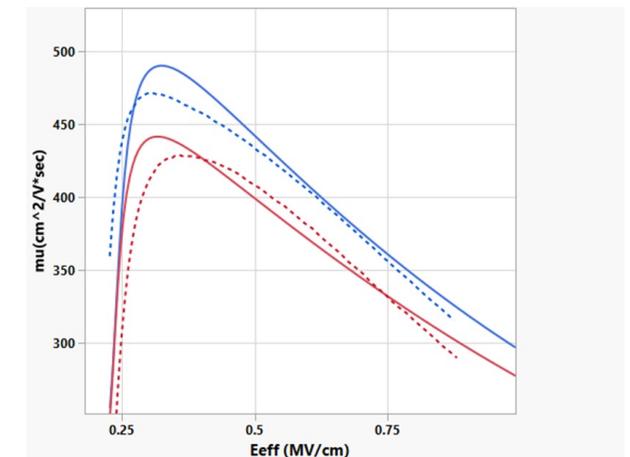
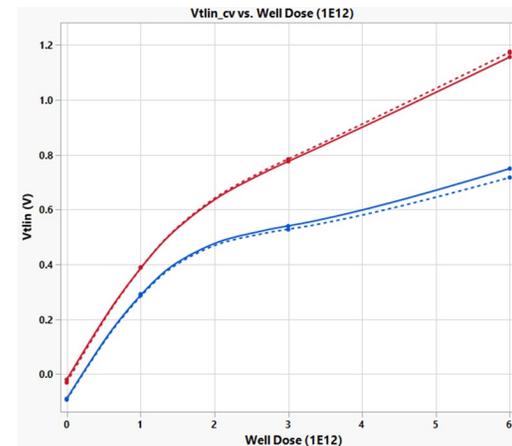
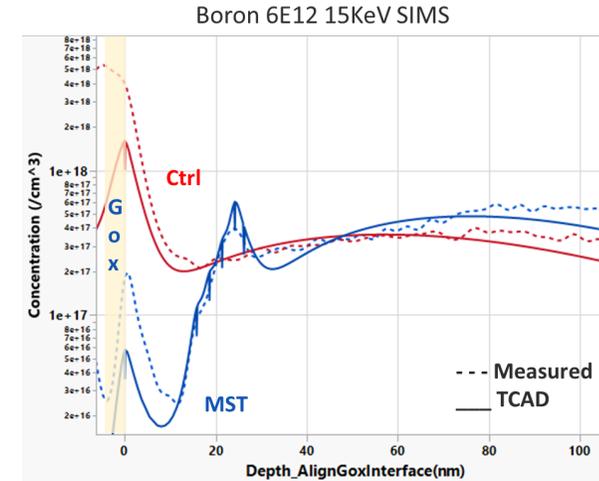
- 300mm Epi deposition
- 200mm Epi deposition
- Wafer cleaning equipment
- Metrology tools
- Advanced wafer handling
- World class clean room facility

▶ Available to deliver customer wafers

Atomera MSTcad™ Progress



- ▶ Leading semiconductor companies use TCAD
- ▶ MST is modelled with a TCAD add-on called MSTcad
- ▶ These plots show silicon verification of MSTcad simulations
- ▶ Enables good electrical match-up for 5V NMOS and MST SP
- ▶ Should speed time to successful results with customers



Atomera Licensees



Atomera Licenses MST Technology to Asahi Kasei Microdevices (AKM)

Highlights:

- Asahi Kasei Microdevices, a Japanese semiconductor manufacturer of high-end specialty integrated circuits (ICs) and sensor products, has licensed Atomera's Mears Silicon Technology™ (MST).

Atomera Licenses MST to STMicroelectronics

Highlights:

- STMicroelectronics, a global semiconductor leader serving customers across the spectrum of electronics applications, has executed an integration license for Atomera's Mears Silicon Technology™ (MST) as a continuation of their R&D phase.
- The phased license agreement provides rights for STMicroelectronics to integrate Atomera MST with their in-house technology.

Atomera to License MST Technology to RF Semiconductor Solution Provider for Mobile 5G Markets

The integration license agreement provides rights to develop a next generation RF platform using MST technology

Atomera and Market Leading Semiconductor Company Sign Joint Development Agreement for Use of MST in Future Devices

New collaboration will leverage Atomera's transistor enhancement technology to develop improvements across the manufacturer's production lines

LOS GATOS, Calif., January 5, 2021 – Atomera Incorporated (Nasdaq: ATOM), a semiconductor materials and technology licensing company, today announced it has entered into a Joint Development Agreement (JDA) with a leading semiconductor provider for integration of Atomera's Mears Silicon Technology (MST) into their silicon fabrication process. The JDA includes a manufacturing license allowing the customer to fabricate semiconductor wafers

AsahiKASEI



**Large fabless
RF semiconductor
company**

**Market Leading
semiconductor
company**

MST1 vs MST2

► MST1

- Blanket technology
- Easy to integrate
- Deposited at beginning of mfg process
- Degraded by high heat in STI/Well module
- Faster time to market for low heat processes
- Used for FinFET, RFSOI, newer process nodes

► MST2

- Selective technology
 - Integrated after STI/Well so avoids highest heat
- More flexible to apply to selected areas only
- Used for 5V, Analog, older process nodes

Wafer manufacturing process

Blank Si wafer

Shallow Trench Isolation (STI) & Well module

Gate module

Source/Drain module

MST1

MST
Si

STI MST STI
Si

STI S Gate MST D STI
Si

MST2

Si

STI Si STI

STI MST STI
Si

STI S Gate MST D STI
Si

MST Matching Performance

- ▶ **Transistor mismatch is an industry problem**
- ▶ **Certain circuit designs benefit from mismatch reduction**
 - A-D convertors
 - SRAM
 - Flash
 - DRAM sense amplifiers
- ▶ **MST can reduce mismatch by more than 50%**
- ▶ **Details available at Atomera's website**
 - blog.atomera.com

